

4-Channel Rail-to-Rail High Current VCOM Buffer

Descriptions

The WS74242D is a 4-channel high performance, high voltage rail-to-rail buffer. It operates up to 20V. The device provides rail-to-rail output and common mode input capability beyond the rails, offering maximum dynamic range at any supply voltage.

The WS74242D provides fast slew rate and settling times, and a high output drive capability of up to 1250mA peak output current. The WS74242D features Over Temperature Protection (OTP), Over Current Protection (OCP) and Output Short Circuit Protection functions, which provide maximum system protection for TFT-LCD panel applications.

The WS74242D is available in the thermally enhanced 14-pin TSSOP package. Standard products are Pb-Free and halogen-Free.

Applications

- TV TFT-LCD Panels
- TFT-LCD Monitors
- Notebooks and Netbooks
- Personal Communication Devices
- Digital Signage
- Touch-Screen Displays
- ADC/DAC Buffers and Active Filters

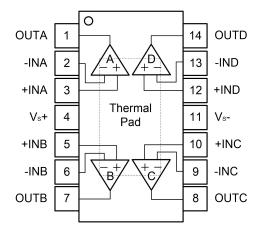
Features

- Beyond the rails input capability
- 1250mA peak output current
- 32MHz 3dB Bandwidth
- Rail-to-rail output swing
- Power supply range from 4V to 20V
- Low supply current per amplifier: 1.3mA
- High Slew Rate: 60V/µs
- Unity-gain stable
- Protection Function
 Over Temperature Protection (OTP)
 Over Current Protection (OCP)
 Output Short Protection

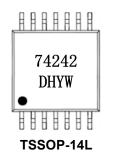




TSSOP-14L



TSSOP-14L Pin configuration (Top view)



Marking 74242 = Device code

Y = Year code

W = Week code

Order information

Device	Package	Shipping	
WS74242DH-14/TR	TSSOP-14L	4000/Reel	
	1330P-14L	&Tape	



Pin Descriptions

Pin Number	Symbol	Descriptions
1	OUTA	Output of Amplifier-A
2	-INA	Inverting Input of Amplifier-A
3	+INA	Non-inverting Input of Amplifier-A
4	V _{S+}	Positive Power Supply
5	+INB	Non-inverting Input of Amplifier-B
6	-INB	Inverting Input of Amplifier-B
7	OUTB	Output of Amplifier-B
8	OUTC	Output of Amplifier-C
9	-INC	Inverting Input of Amplifier-C
10	+INC	Non-inverting Input of Amplifier-C
11	Vs-	Negative Power Supply.
12	+IND	Non-inverting Input of Amplifier-D
13	-IND	Inverting Input of Amplifier-D
14	OUTD	Output of Amplifier-D
ГР	Thermal	Exposed Pad. The exposed pad must be soldered to a large PCB and
EP	Pad	connected to system ground for maximum thermal dissipation.

Absolute Maximum Ratings⁽¹⁾

Parameter	Symbol	Value	Unit
Supply Voltage, ([V _{S+}] - [V _{S-}])	Vs	22	V
Input Common Mode Voltage Range	V _{ICR}	(V _{S-})-0.3 to (V _{S+})+0.3	V
Operating Free-Air Temperature Range	T _A	-40 to 85	°C
Operating Junction Temperature Range	TJ	-40 to 150	°C
Storage Temperature Range	T _{STG}	-65 to 150	°C
Junction to Ambient Thermal Resistance	$\theta_{JA}^{(3)}$	43	
Junction to Board Thermal Resistance	θ _{JB} ⁽³⁾	17.2	°C/W
Junction to Case (Top) Thermal Resistance	θ _{JCtop} ⁽³⁾	θ _{JCtop} ⁽³⁾ 16.3	
Junction to Case (Bottom) Thermal Resistance	θ _{JCbot} ⁽³⁾	3.7	

Note:

- 1. Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device.
- 2. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- 3. Single component mounted on 2oz, 1.5*1.5 inch² FR4 PCB with 1.0*1.0 inch² Cu area.

ESD, Electrostatic Discharge Protection

Symbol	Parameter	Condition	Minimum level	Unit
	Human Body Model ESD of		±6000	
HBM	Output Pins	MIL-STD-883H Method 3015.8	20000	v
	Human Body Model ESD of	JEDEC-EIA/JESD22-A114A	±3000	v
	Other Pins		±3000	
CDM	Charged Device Model ESD	JEDEC-EIA/JESD22-C101E	±2000	V
MM	Machine Model ESD	JEDEC-EIA/JESD22-A115	±400	V



Electronics Characteristics

 V_{S+} = 19V, V_{S-} = 0V, V_{INx+} = 9.5V, 4CH unity gain (V_{INx-} = V_{OUTx}), with R_L = 10k Ω and C_L = 10pF unless otherwise specified. Typical values are tested at +25°C ambient temperature

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
(Vs+)-(Vs-)	Supply Voltage Range		4	-	19	V
ls	Supply Current		-	5.2	8	mA
Vos	Input Offset Voltage		-15	+3	+15	mV
IB	Input Bias Current		-0.1	-	+0.1	nA
V _{OL}	Output Swing Low	V _{INx} + = 0V, I∟=-5mA	-	18	25	mV
V _{OH}	Output Swing High	V _{INx} + = 18V, I∟=+5mA	-	23	30	mV
lo	Continue Output Current	Before OTP	-	±400	-	mA
I _{Peak}	Peak Output Current		-	±1250	-	mA
SR	Slew Rate	0.5V to 17.5V, 20% to 80%	-	60	-	V/µs
BW	Bandwidth	-3dB	-	32	-	MHz
A _{VOL}	Open-Loop Gain	R∟ = 10kΩ	-	100	-	dB
PSRR	Power Supply Rejection Ration	6V < (V _S +)-(V _S -) < 18V	90	116	-	dB
CMIR	Common-Mode Input Range		-0.1	-	19.1	V
CMRR	Common-Mode Rejection Ration	RL = 10kΩ	-	78	-	dB
T _{SD}	Thermal Shutdown		-	150	-	°C



Applications Information Unused Amplifiers

It is strongly recommended to configure any unused amplifiers as unity gain buffer and directly tie the non-inverting input to the ground plane.

Protection Functions

The WS74242D features over temperature protection (OTP), over current protection (OCP), and output short circuit protection functions. These features provide maximum system protection for demanding TFT LCD panel applications.

The WS74242D limits the peak output current to ± 1250 mA and the continue output current to ± 400 mA for normal operation. If the output of the WS74242D is shorted to V_{S-} or V_{S+}, the over current protection (OCP) mechanism will be activate to regulate the power dissipation to prevent overstressing of the power bus. The over temperature protection (OTP) function of the WS74242D monitors the silicon junction temperature. When the junction temperature exceeds 150°C, the OTP protection circuit disables normal operation to lower the chip operating temperature.

The synergistic operation of the OTP, OCP, peak output current limit and continue output current limit functions provides maximum output short protection for the WS74242D.

Power Dissipation

The WS74242D design is optimized to deliver maximum output current driving capability for TFT LCD panel applications. Due to its robust protection features, the WS74242D can endure a momentary output short to ground (or VS-).

Due to its high current driving capability, it is possible for the junction temperature to exceed 150°C under certain output current load conditions. Therefore, it is very important to calculate the WS74242D's maximum junction temperature and maximum power dissipation for the application to make sure that the junction temperature does not exceed 150°C or maximum package power rating to ensure the device stays in the safe operating region.

Driving Capacitive Loads

The strong output current driving capability of the WS74242D allows for a high slew rate even with large capacitive loads. Sometimes there is output peaking for certain application loads and application configurations. If less output peaking is desired for these applications, a small damping resistor (usually between 2Ω and 15Ω) can be connected in series between the output of WS74242D and the load. However, this topology will reduce the gain slightly.

Another method of reducing output peaking is to add a snubber circuit at the output. A snubber circuit consists of a resistor (such as $100\Omega - 200\Omega$) in series with a capacitor (such as 10nF), which improves output settling time and reduces peaking. The advantage of this topology is that it draws no DC current nor does it reduce the gain.

Bypass Capacitors

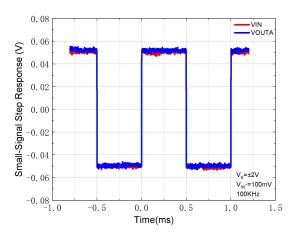
For stability while driving load transients, and to minimize the noise to the system, use a 10μ F capacitor for the V_{S+} supply. Connect this bypass capacitor as close as possible to the input V_{S+}.

Layout

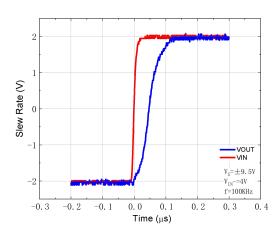
Connect the exposed pad of the device to the V_{S-} or GND plane for best thermal dissipation performance, or low thermal resistance. In typical application, V_{S-} is connected to ground.

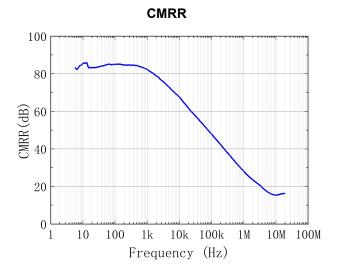


Typical Characteristics T_A=25°C, V_s=5V, V_{CM}=V_s/2, unless otherwise noted Small-Signal Step Response

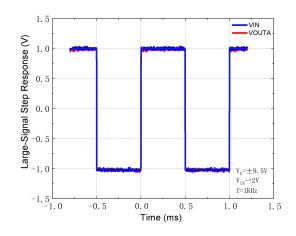




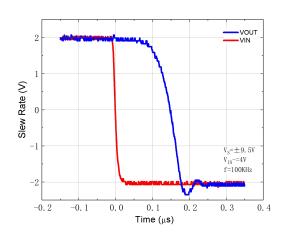




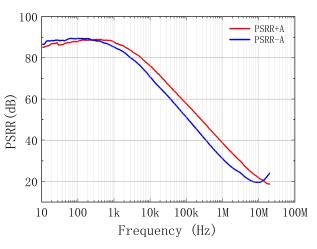






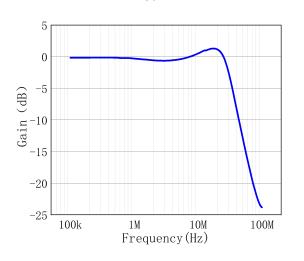


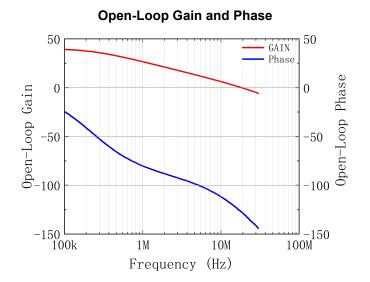






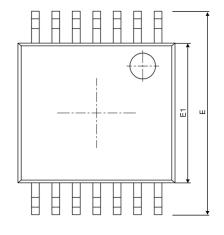
Typical Characteristics $T_A=25^{\circ}C$, $V_S=5V$, $V_{CM}=V_S/2$, unless otherwise noted -3dB

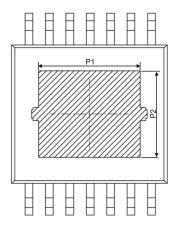


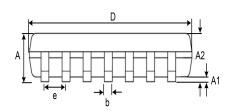


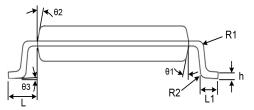


PACKAGE OUTLINE DIMENSIONS







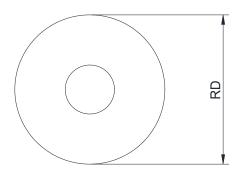


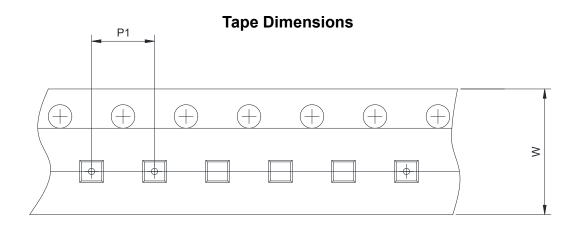
Symbol	Dimensions In Millimeters (mm)			
	Min.	Тур.	Max.	
A	-	-	1.20	
A1	0.05	-	0.15	
A2	0.80	-	1.05	
D	4.90	-	5.10	
е		0.65 BSC		
b	0.19	-	0.30	
E	6.25	-	6.55	
E1	4.30	-	4.50	
P1	3.30	-	3.70	
P2	2.90	-	3.20	
L	-	-	1.00	
L1	0.45	-	0.75	
R1	-	0.15	-	
R2	-	0.15	-	
θ1	-	12°	-	
θ2	-	12°	-	
θ3	0°	-	8°	
h	0.09	-	0.20	



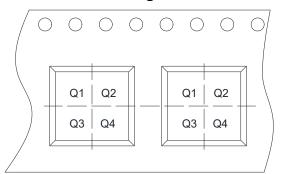
TAPE AND REEL INFORMATION

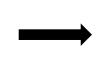
Reel Dimensions





Quadrant Assignments For PIN1 Orientation In Tape





User Direction of Feed

RD	Reel Dimension	Tinch	🔽 13inch		
W	Overall width of the carrier tape	🔲 8mm	🔽 12mm		
P1	Pitch between successive cavity centers	🔲 2mm	🔲 4mm	🗹 8mm	
Pin1	Pin1 Quadrant	🗹 Q1	🗖 Q2	C Q3	🗖 Q4

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Buffers & Line Drivers category:

Click to view products by Will Semiconductor manufacturer:

Other Similar products are found below :

LXV200-024SW 74AUP2G34FW3-7 HEF4043BP NL17SG125DFT2G NLU1GT126CMUTCG CD4041UBE 54FCT240CTDB 74HCT540N DS14C88N 070519XB NL17SZ07P5T5G 74LVC2G17FW4-7 CD4502BE 5962-8982101PA 61446R00 NL17SH17P5T5G NLV37WZ17USG 74HCT126T14-13 74VHC9126FT(BJ) RHRXH162244K1 74AUP1G34FW5-7 74AUP1G07FW5-7 74LVC1G126FW4-7 74LVC2G126RA3-7 74LVCE1G125FZ4-7 54FCT240TLB NLX3G16DMUTCG NLX2G06AMUTCG LE87100NQCT LE87285NQC LE87290YQC LE87290YQCT 74AUP1G125FW5-7 NLU2G16CMUTCG MC74LCX244MN2TWG NL17SG17P5T5G NLV74HC125ADR2G NLVHCT245ADTR2G NLVVHC1G126DFT2G EL5623IRZ ISL15102AIRZ-T13 ISL1539IRZ-T13 MC100EP17MNG MC74HCT365ADR2G MC74LCX244ADTR2G NL27WZ126US NL37WZ16US NLU1G07MUTCG NLU2G07MUTCG NLX3G17BMX1TCG